

40V P-Channel Enhancement Mode MOSFET

Voltage

-40 V

Current

-14 A

Features

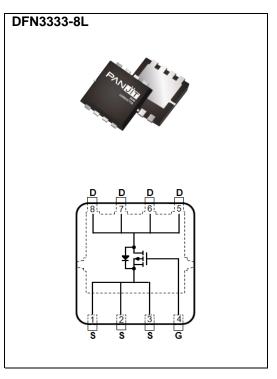
- $R_{DS(ON)}$, V_{GS} @-10V, I_D @-8A<45m Ω
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-4A<68m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	-40	\ /	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	Tc=25°C	I _D	-14	А	
	Tc=100°C		-9		
Pulsed Drain Current(Note 1)	Tc=25°C	I _{DM}	-56		
Power Dissipation	Tc=25°C	Po	15	10/	
	Tc=100°C		6	W	
Continuous Drain Current	T _A =25°C	l _D	-5		
	T _A =70°C		-4	Α	
Power Dissipation	T _A =25°C	ſ	2.1	W	
Power Dissipation	T _A =70°C	Pb	1.3		
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	R _{0JC}	8.33	°C/W	
	Junction to Ambient	$R_{\theta JA}$	59.5		

Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-40	-	-	- v
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.65	-2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-8A	-	37	45	mΩ
		V _{GS} =-4.5V, I _D =-4A	-	57	68	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =-40V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	V _{DS} =-20V, I _D =-5A, V _{GS} =-4.5V ^(Note 2,3)	-	8.3	-	nC
Gate-Source Charge	Qgs		-	2.6	-	
Gate-Drain Charge	Q_{gd}		-	2.7	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1MHZ	-	929	-	pF
Output Capacitance	Coss		-	84	-	
Reverse Transfer Capacitance	Crss		-	60	-	
Turn-On Delay Time	td _(on)	V_{DS} =-20V, I_{D} =-1A, V_{GS} =-4.5V, R_{G} =6 Ω (Note 2,3)	-	26	-	
Turn-On Rise Time	t _r		-	27	-	ns
Turn-Off Delay Time	td _(off)		-	66	-	
Turn-Off Fall Time	t _f		-	40	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-14	А
Diode Forward Current	Is					
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.75	-1	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

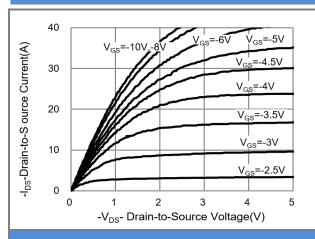


Fig.1 On-Region Characteristics

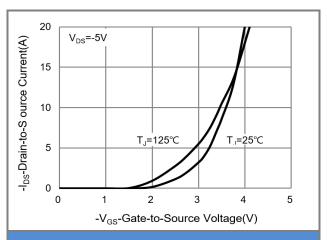


Fig.2 Transfer Characteristics

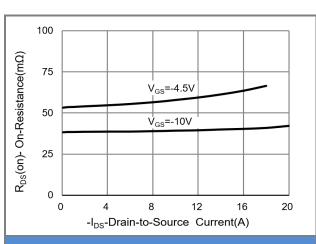


Fig.3 On-Resistance vs. Drain Current

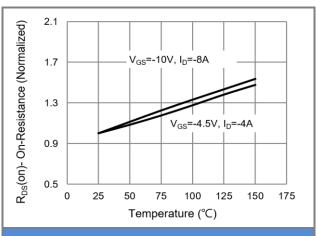


Fig.4 On-Resistance vs. Junction temperature

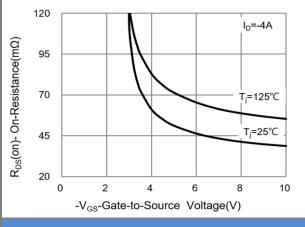


Fig.5 On-Resistance Variation with V_{GS}

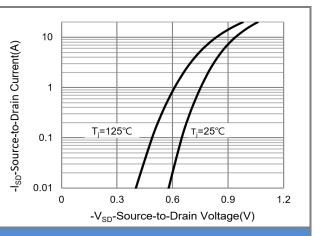


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

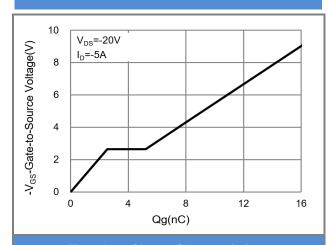


Fig.7 Gate-Charge Characteristics

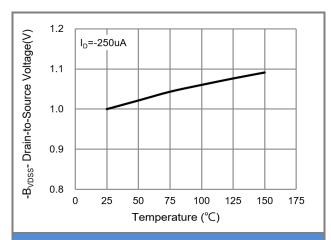


Fig.8 Breakdown Voltage Variation vs. Temperature

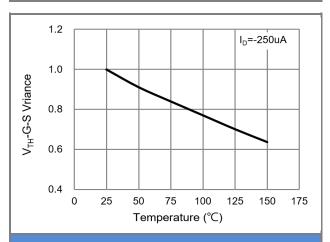


Fig.9 Threshold Voltage Variation with Temperature

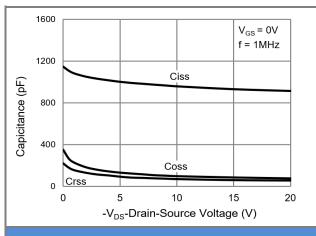


Fig.10 Capacitance vs. Drain-Source Voltage

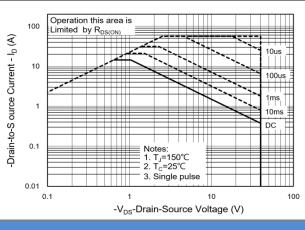


Fig.11 Maximum Safe Operating Area

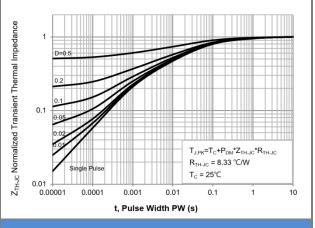


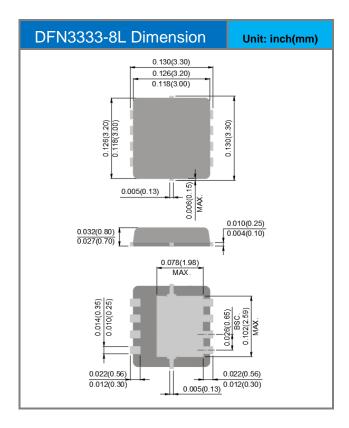
Fig.12 Normalized Transient Thermal Impedance

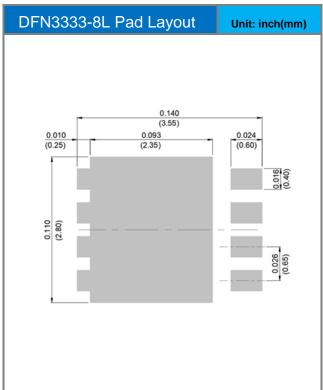


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4453P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4453	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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